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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	e200z4
Core Size	32-Bit Single-Core
Speed	120MHz
Connectivity	CANbus, Ethernet, FlexRay, I <sup>2</sup> C, LINbus, SPI
Peripherals	DMA, I <sup>2</sup> S, POR, WDT
Number of I/O	129
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	256K x 8
Voltage - Supply (Vcc/Vdd)	3.15V ~ 5.5V
Data Converters	A/D 36x10b, 16x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	176-LQFP Exposed Pad
Supplier Device Package	176-LQFP (24x24)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5745bfk1avku2">https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5745bfk1avku2</a>

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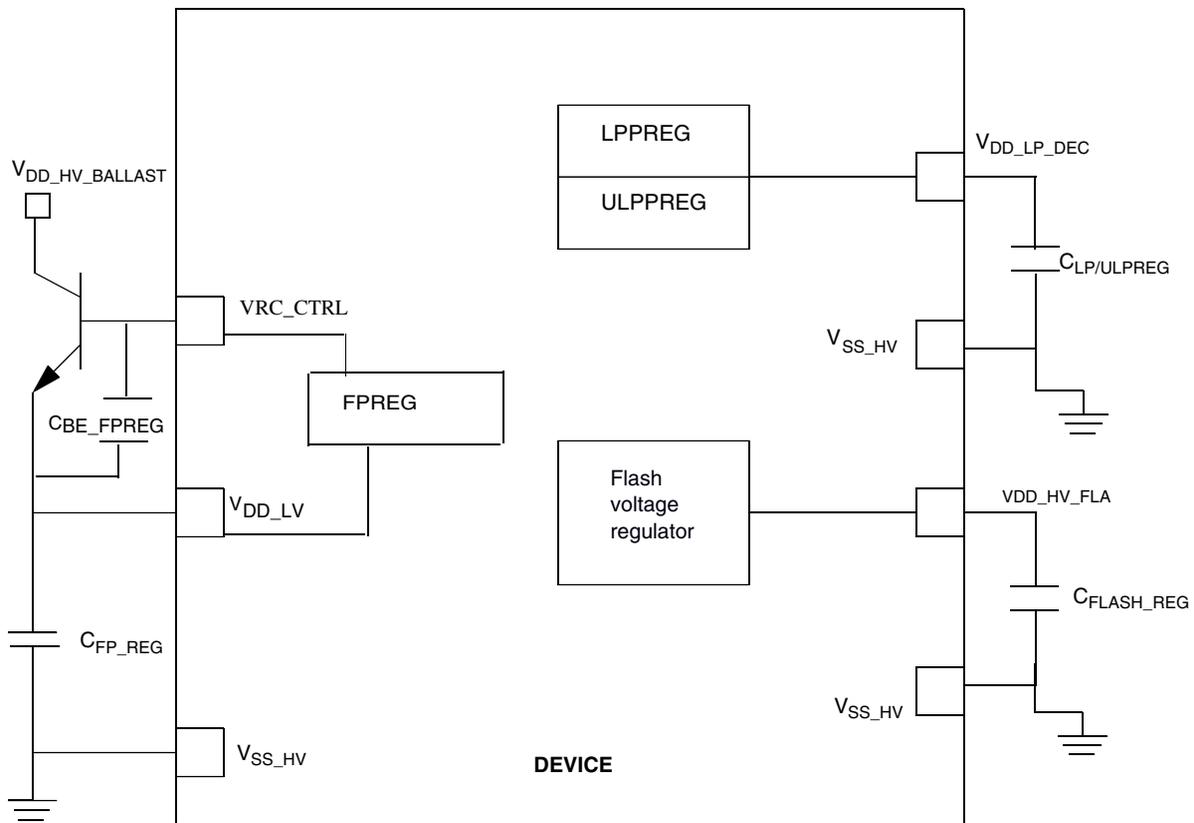


Figure 2. Voltage regulator capacitance connection

**NOTE**

On BGA, VSS\_LV and VSS\_HV have been joined on substrate and renamed as VSS.

Table 8. Voltage regulator electrical specifications

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
C <sub>fp_reg</sub> <sup>1</sup>	External decoupling / stability capacitor	Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.	1.32	2.2 <sup>2</sup>	3	μF
	Combined ESR of external capacitor	—	0.001	—	0.03	Ohm
C <sub>lp/ulp_reg</sub>	External decoupling / stability capacitor for internal low power regulators	Min, max values shall be granted with respect to tolerance, voltage, temperature, and aging variations.	0.8	1	1.4	μF
	Combined ESR of external capacitor	—	0.001	—	0.1	Ohm
C <sub>be_fpreg</sub> <sup>3</sup>	Capacitor in parallel to base-emitter	BCP68 and BCP56		3.3		nF
		MJD31		4.7		

Table continues on the next page...

## General

5.
  1. For VDD\_HV\_x, 1µf on each side of the chip
    - a. 0.1 µf close to each VDD/VSS pin pair.
    - b. 10 µf near for each power supply source
    - c. For VDD\_LV, 0.1µf close to each VDD/VSS pin pair is required. Depending on the the selected regulation mode, this amount of capacitance will need to be subtracted from the total capacitance required by the regulator for e.g., as specified by CFP\_REG parameter.
  2. For VDD\_LV, 0.1µf close to each VDD/VSS pin pair is required. Depending on the the selected regulation mode, this amount of capacitance will need to be subtracted from the total capacitance required by the regulator for e.g., as specified by CFP\_REG parameter
6. Only applicable to ADC1
7. In external ballast configuration the following must be ensured during power-up and power-down (Note: If V<sub>DD\_HV\_BALLAST</sub> is supplied from the same source as VDD\_HV\_A this condition is implicitly met):
  - During power-up, V<sub>DD\_HV\_BALLAST</sub> must have met the min spec of 2.25V before VDD\_HV\_A reaches the POR\_HV\_RISE min of 2.75V.
  - During power-down, V<sub>DD\_HV\_BALLAST</sub> must not drop below the min spec of 2.25V until VDD\_HV\_A is below POR\_HV\_FALL min of 2.7V.

### NOTE

For a typical configuration using an external ballast transistor with separate supply for VDD\_HV\_A and the ballast collector, a bulk storage capacitor (as defined in [Table 8](#)) is required on VDD\_HV\_A close to the device pins to ensure a stable supply voltage.

Extra care must be taken if the VDD\_HV\_A supply is also being used to power the external ballast transistor or the device is running in internal regulation mode. In these modes, the inrush current on device Power Up or on exit from Low Power Modes is significant and may case the VDD\_HV\_A voltage to drop resulting in an LVD reset event. To avoid this, the board layout should be optimized to reduce common trace resistance or additional capacitance at the ballast transistor collector (or VDD\_HV\_A pins in the case of internal regulation mode) is required. NXP recommends that customers simulate the external voltage supply circuitry.

In all circumstances, the voltage on VDD\_HV\_A must be maintained within the specified operating range (see [Recommended operating conditions](#)) to prevent LVD events.

**Table 9. Voltage monitor electrical characteristics (continued)**

Symbol	Parameter	State	Conditions	Configuration			Threshold			Unit
				Power Up <sup>1</sup>	Mask Opt <sup>2,2</sup>	Reset Type	Min	Typ	Max	V
V <sub>LVD_LV_PD</sub> 2_cold	LV supply low voltage monitoring, detecting at the device pin	Fall	Untrimmed	No	Yes	Function al	Disabled at Start			
			Trimmed				1.1400	1.1550	1.1750	V
		Rise	Untrimmed	Disabled at Start						
			Trimmed	1.1600	1.1750	1.1950	V			

1. All monitors that are active at power-up will gate the power up recovery and prevent exit from POWERUP phase until the minimum level is crossed. These monitors can in some cases be masked during normal device operation, but when active will always generate a destructive reset.
2. Voltage monitors marked as non maskable are essential for device operation and hence cannot be masked.
3. There is no voltage monitoring on the V<sub>DD\_HV\_ADC0</sub>, V<sub>DD\_HV\_ADC1</sub>, V<sub>DD\_HV\_B</sub> and V<sub>DD\_HV\_C</sub> I/O segments. For applications requiring monitoring of these segments, either connect these to V<sub>DD\_HV\_A</sub> at the PCB level or monitor externally.

## 4.5 Supply current characteristics

Current consumption data is given in the following table. These specifications are design targets and are subject to change per device characterization.

### NOTE

The ballast must be chosen in accordance with the ballast transistor supplier operating conditions and recommendations.

**Table 10. Current consumption characteristics**

Symbol	Parameter	Conditions <sup>1</sup>	Min	Typ	Max	Unit
I <sub>DD_BODY_1</sub> 2, 3	RUN Body Mode Profile Operating current	LV supply + HV supply + HV Flash supply + 2 x HV ADC supplies <sup>4,4</sup> T <sub>a</sub> = 125°C <sup>5,5</sup> V <sub>DD_LV</sub> = 1.25 V V <sub>DD_HV_A</sub> = 5.5V SYS_CLK = 80MHz	—	—	147	mA
		T <sub>a</sub> = 105°C	—	—	142	mA
		T <sub>a</sub> = 85 °C	—	—	137	mA

Table continues on the next page...

Table 10. Current consumption characteristics (continued)

Symbol	Parameter	Conditions <sup>1</sup>	Min	Typ	Max	Unit
I <sub>DD_BODY_2</sub> 6	RUN Body Mode Profile Operating current	LV supply + HV supply + HV Flash supply + 2 x HV ADC supplies <sup>4</sup> T <sub>a</sub> = 125°C <sup>5</sup> V <sub>DD_LV</sub> = 1.25 V VDD_HV_A = 5.5V SYS_CLK = 160MHz	—	—	246	mA
		T <sub>a</sub> = 105°C	—	—	235	mA
		T <sub>a</sub> = 85°C	—	—	210	mA
I <sub>DD_BODY_3</sub> 7	RUN Body Mode Profile Operating current	LV supply + HV supply + HV Flash supply + 2 x HV ADC supplies <sup>4</sup> T <sub>a</sub> = 125 °C <sup>5</sup> V <sub>DD_LV</sub> = 1.25 V VDD_HV_A = 5.5V SYS_CLK = 120MHz	—	—	181	mA
		T <sub>a</sub> = 105 °C	—	—	176	mA
		T <sub>a</sub> = 85°C	—	—	171	mA
I <sub>DD_BODY_4</sub> <sup>8</sup>	RUN Body Mode Profile Operating current	LV supply + HV supply + HV Flash supply + 2 x HV ADC supplies <sup>4</sup> T <sub>a</sub> = 125 °C <sup>5</sup> V <sub>DD_LV</sub> = 1.25 V VDD_HV_A = 5.5V SYS_CLK = 120MHz	—	—	264	mA
		T <sub>a</sub> = 105 °C	—	—	176	mA
		T <sub>a</sub> = 85 °C	—	—	171	mA
I <sub>DD_STOP</sub>	STOP mode Operating current	T <sub>a</sub> = 125 °C <sup>9</sup> V <sub>DD_LV</sub> = 1.25 V	—	—	49	mA
		T <sub>a</sub> = 105 °C V <sub>DD_LV</sub> = 1.25 V	—	10.6	—	
		T <sub>a</sub> = 85 °C V <sub>DD_LV</sub> = 1.25 V	—	8.1	—	
		T <sub>a</sub> = 25 °C V <sub>DD_LV</sub> = 1.25 V	—	4.6	—	

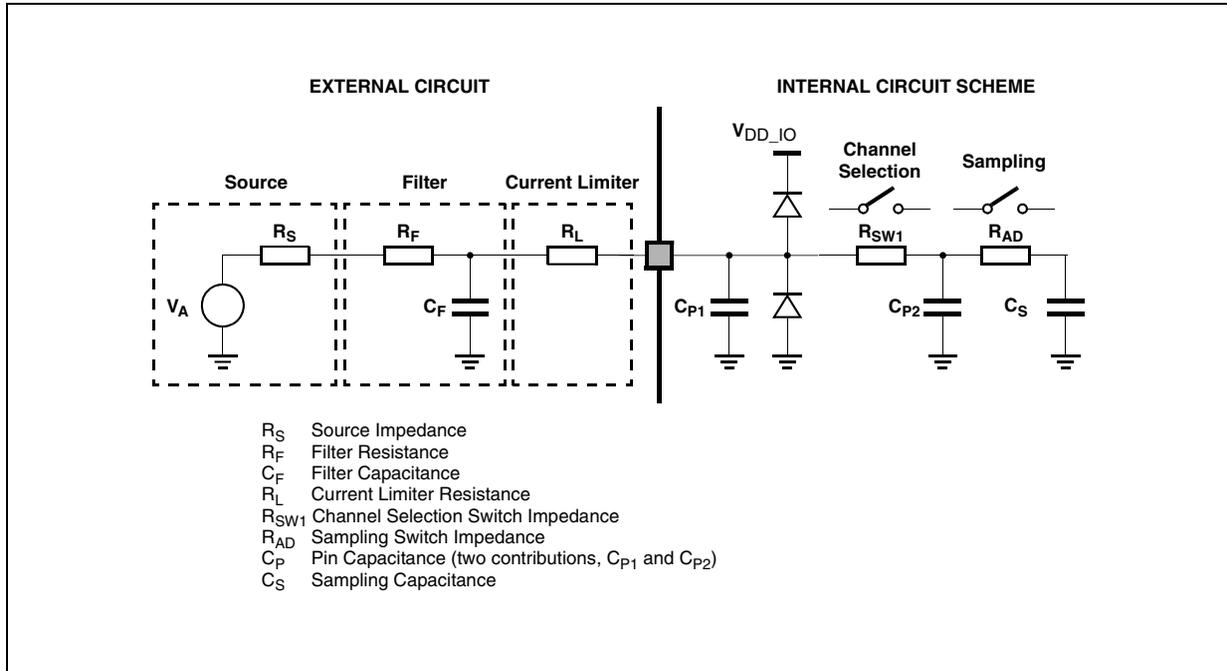
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**Table 10. Current consumption characteristics (continued)**

Symbol	Parameter	Conditions <sup>1</sup>	Min	Typ	Max	Unit
$I_{DD\_HV\_ADC\_REF}$ <sup>10, 11, 11</sup>	ADC REF Operating current	$T_a = 125\text{ }^\circ\text{C}$ <sup>5</sup> 2 ADCs operating at 80 MHz $V_{DD\_HV\_ADC\_REF} = 5.5\text{ V}$	—	200	400	$\mu\text{A}$
		$T_a = 105\text{ }^\circ\text{C}$ 2 ADCs operating at 80 MHz $V_{DD\_HV\_ADC\_REF} = 5.5\text{ V}$	—	200	—	
		$T_a = 85\text{ }^\circ\text{C}$ 2 ADCs operating at 80 MHz $V_{DD\_HV\_ADC\_REF} = 5.5\text{ V}$	—	200	—	
		$T_a = 25\text{ }^\circ\text{C}$ 2 ADCs operating at 80 MHz $V_{DD\_HV\_ADC\_REF} = 3.6\text{ V}$	—	200	—	
$I_{DD\_HV\_ADCx}$ <sup>11</sup>	ADC HV Operating current	$T_a = 125\text{ }^\circ\text{C}$ <sup>5</sup> ADC operating at 80 MHz $V_{DD\_HV\_ADC} = 5.5\text{ V}$	—	1.2	2	mA
		$T_a = 25\text{ }^\circ\text{C}$ ADC operating at 80 MHz $V_{DD\_HV\_ADC} = 3.6\text{ V}$	—	1	2	
$I_{DD\_HV\_FLASH}$ <sup>12</sup>	Flash Operating current during read access	$T_a = 125\text{ }^\circ\text{C}$ <sup>5</sup> 3.3 V supplies 160 MHz frequency	—	40	45	mA
		$T_a = 105\text{ }^\circ\text{C}$ 3.3 V supplies 160 MHz frequency	—	40	45	
		$T_a = 85\text{ }^\circ\text{C}$ 3.3 V supplies 160 MHz frequency	—	40	45	

- The content of the Conditions column identifies the components that draw the specific current.
- Single e200Z4 core cache disabled @80 MHz, no FlexRay, no ENET, 2 x CAN, 8 LINFlexD, 2 SPI, ADC0 and 1 used constantly, no HSM, Memory: 2M flash, 128K RAM RUN mode, Clocks: FIRC on, XOSC, PLL on, SIRC on for TOD, no 32KHz crystal (TOD runs off SIRC).
- Recommended Transistors:MJD31 @ 85°C, 105°C and 125°C. In case of internal ballast mode, it is expected that the external ballast is not mounted and BAL\_SELECT\_INT pin is tied to VDD\_HV\_A supply on board. Internal ballast can be used for all use cases with current consumption upto 150mA
- The power consumption does not consider the dynamic current of I/Os
- $T_j=150^\circ\text{C}$ . Assumes  $T_a=125^\circ\text{C}$ 
  - Assumes maximum  $\theta_{JA}$  of 2s2p board. See [Thermal attributes](#)
- e200Z4 core, 160MHz, cache enabled; e200Z2 core , 80MHz, no FlexRay, no ENET, 7 CAN, 16 LINFlexD, 4 SPI, 1x ADC used constantly, includes HSM at start-up / periodic use, Memory: 3M flash, 256K RAM, Clocks: FIRC on, XOSC on, PLL on, SIRC on, no 32KHz crystal
- e200Z4 core, 120MHz, cache enabled; e200Z2 core, 60MHz; no FlexRay, no ENET, 7 CAN, 16 LINFlexD, 4 SPI, 1x ADC used constantly, includes HSM at start-up / periodic use, Memory: 3M flash, 128K RAM, Clocks: FIRC on, XOSC on, PLL on, SIRC on, no 32KHz crystal

### 6.1.1.1 Input equivalent circuit and ADC conversion characteristics



**Figure 6. Input equivalent circuit**

**NOTE**

The ADC performance specifications are not guaranteed if two ADCs simultaneously sample the same shared channel.

**Table 20. ADC conversion characteristics (for 12-bit)**

Symbol	Parameter	Conditions	Min	Typ <sup>1</sup>	Max	Unit
$f_{CK}$	ADC Clock frequency (depends on ADC configuration) (The duty cycle depends on AD_CK <sup>2</sup> frequency)	—	15.2	80	80	MHz
$f_s$	Sampling frequency	80 MHz	—	—	1.00	MHz
$t_{sample}$	Sample time <sup>3</sup>	80 MHz @ 100 ohm source impedance	250	—	—	ns
$t_{conv}$	Conversion time <sup>4</sup>	80 MHz	700	—	—	ns
$t_{total\_conv}$	Total Conversion time $t_{sample} + t_{conv}$ (for standard and extended channels)	80 MHz	1.5 <sup>5</sup>	—	—	$\mu$ s
	Total Conversion time $t_{sample} + t_{conv}$ (for precision channels)		1	—	—	
$C_S^{6,6}$	ADC input sampling capacitance	—	—	3	5	pF
$C_{P1}^6$	ADC input pin capacitance 1	—	—	—	5	pF
$C_{P2}^6$	ADC input pin capacitance 2	—	—	—	0.8	pF
$R_{SW1}^6$	Internal resistance of analog source	$V_{REF}$ range = 4.5 to 5.5 V	—	—	0.3	k $\Omega$
		$V_{REF}$ range = 3.15 to 3.6 V	—	—	875	$\Omega$

Table continues on the next page...

**Table 28. Jitter calculation (continued)**

Type of jitter	Jitter due to Supply Noise (ps) $J_{SN}^1$	Jitter due to Fractional Mode (ps) $J_{SDM}^2$	Jitter due to Fractional Mode $J_{SSCG}$ (ps) $^3$	1 Sigma Random Jitter $J_{RJ}$ (ps) $^4$	Total Period Jitter (ps)
Long Term Jitter (Integer Mode)				40	+/(N x $J_{RJ}$ )
Long Term jitter (Fractional Mode)				100	+/(N x $J_{RJ}$ )

1. This jitter component is due to self noise generated due to bond wire inductances on different PLL supplies. The jitter value is valid for inductor value of 5nH or less each on VDD\_LV and VSS\_LV.
2. This jitter component is added when the PLL is working in the fractional mode.
3. This jitter component is added when the PLL is working in the Spread Spectrum Mode. Else it is 0.
4. The value of N is dependent on the accuracy requirement of the application. See [Table 29](#)

**Table 29. Percentage of sample exceeding specified value of jitter**

N	Percentage of samples exceeding specified value of jitter (%)
1	31.73
2	4.55
3	0.27
4	$6.30 \times 1e-03$
5	$5.63 \times 1e-05$
6	$2.00 \times 1e-07$
7	$2.82 \times 1e-10$

## 6.3 Memory interfaces

### 6.3.1 Flash memory program and erase specifications

#### NOTE

All timing, voltage, and current numbers specified in this section are defined for a single embedded flash memory within an SoC, and represent average currents for given supplies and operations.

[Table 30](#) shows the estimated Program/Erase times.

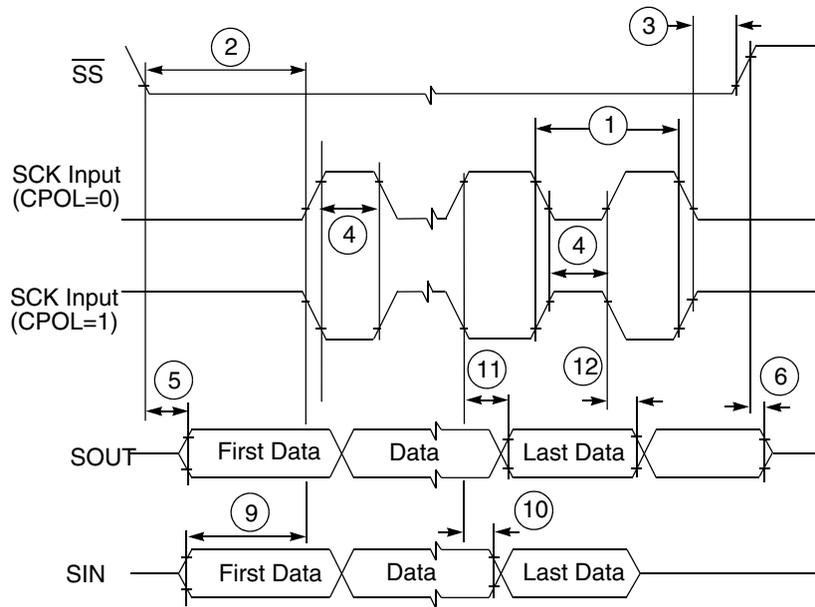
## 6.4 Communication interfaces

### 6.4.1 DSPI timing

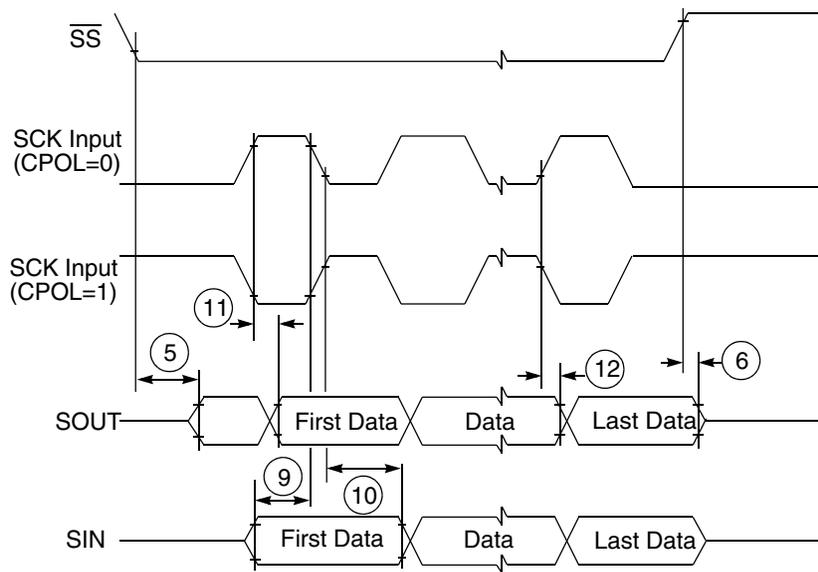
Table 35. DSPI electrical specifications

No	Symbol	Parameter	Conditions	High Speed Mode		low Speed mode		Unit
				Min	Max	Min	Max	
1	$t_{SCK}$	DSPI cycle time	Master (MTFE = 0)	25	—	50	—	ns
			Slave (MTFE = 0)	40	—	60	—	
2	$t_{CSC}$	PCS to SCK delay	—	16	—	—	—	ns
3	$t_{ASC}$	After SCK delay	—	16	—	—	—	ns
4	$t_{SDC}$	SCK duty cycle	—	$t_{SCK}/2 - 10$	$t_{SCK}/2 + 10$	—	—	ns
5	$t_A$	Slave access time	SS active to SOUT valid	—	40	—	—	ns
6	$t_{DIS}$	Slave SOUT disable time	SS inactive to SOUT High-Z or invalid	—	10	—	—	ns
7	$t_{PCSC}$	PCSx to PCSS time	—	13	—	—	—	ns
8	$t_{PASC}$	PCSS to PCSx time	—	13	—	—	—	ns
9	$t_{SUI}$	Data setup time for inputs	Master (MTFE = 0)	NA	—	20	—	ns
			Slave	2	—	2	—	
			Master (MTFE = 1, CPHA = 0)	15	—	8 <sup>1, 1</sup>	—	
			Master (MTFE = 1, CPHA = 1)	15	—	20	—	
10	$t_{HI}$	Data hold time for inputs	Master (MTFE = 0)	NA	—	-5	—	ns
			Slave	4	—	4	—	
			Master (MTFE = 1, CPHA = 0)	0	—	11 <sup>1</sup>	—	
			Master (MTFE = 1, CPHA = 1)	0	—	-5	—	
11	$t_{SUO}$	Data valid (after SCK edge)	Master (MTFE = 0)	—	NA	—	4	ns
			Slave	—	15	—	23	
			Master (MTFE = 1, CPHA = 0)	—	4	—	16 <sup>1</sup>	
			Master (MTFE = 1, CPHA = 1)	—	4	—	4	

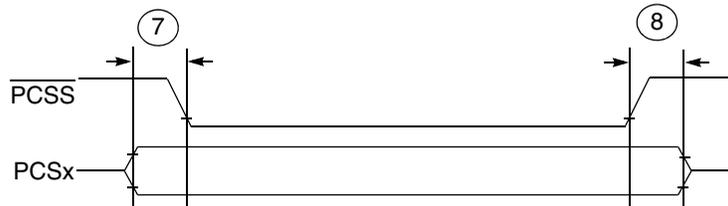
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**Figure 14. DSPI modified transfer format timing – slave, CPHA = 0**



**Figure 15. DSPI modified transfer format timing — slave, CPHA = 1**

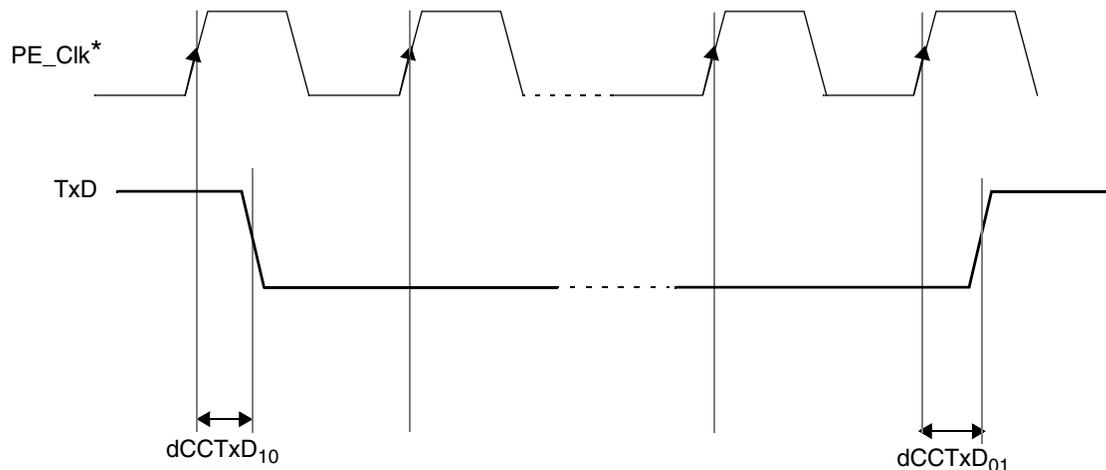


**Figure 16. DSPI PCS strobe (PCSS) timing**

**Table 39. TxD output characteristics (continued)**

Name	Description <sup>1</sup>	Min	Max	Unit
dCCTxD <sub>01</sub>	Sum of delay between Clk to Q of the last FF and the final output buffer, rising edge	—	25	ns
dCCTxD <sub>10</sub>	Sum of delay between Clk to Q of the last FF and the final output buffer, falling edge	—	25	ns

1. All parameters specified for  $V_{DD\_HV\_IOx} = 3.3\text{ V} \pm 5\%$ ,  $\pm 10\%$ ,  $T_J = -40\text{ }^\circ\text{C} / 150\text{ }^\circ\text{C}$ , TxD pin load maximum 25 pF.
2. For 3.3 V  $\pm 10\%$  operation, this specification is 10 ns.



\*FlexRay Protocol Engine Clock

**Figure 20. TxD Signal propagation delays**

#### 6.4.2.4 RxD

**Table 40. RxD input characteristic**

Name	Description <sup>1</sup>	Min	Max	Unit
C_CCRxD	Input capacitance on RxD pin	—	7	pF
uCCLogic_1	Threshold for detecting logic high	35	70	%
uCCLogic_0	Threshold for detecting logic low	30	65	%
dCCRxD <sub>01</sub>	Sum of delay from actual input to the D input of the first FF, rising edge	—	10	ns
dCCRxD <sub>10</sub>	Sum of delay from actual input to the D input of the first FF, falling edge	—	10	ns

1. All parameters specified for VDD\_HV\_IOx = 3.3 V -5%, ±10%, TJ = -40 oC / 150 oC.

### 6.4.3 Ethernet switching specifications

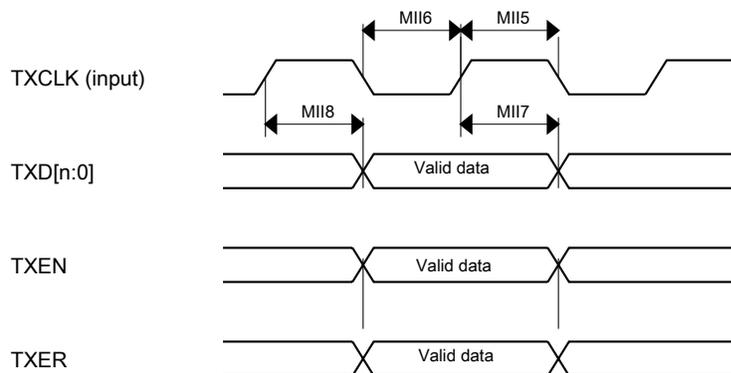
The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

#### 6.4.3.1 MII signal switching specifications

The following timing specs meet the requirements for MII style interfaces for a range of transceiver devices.

**Table 41. MII signal switching specifications**

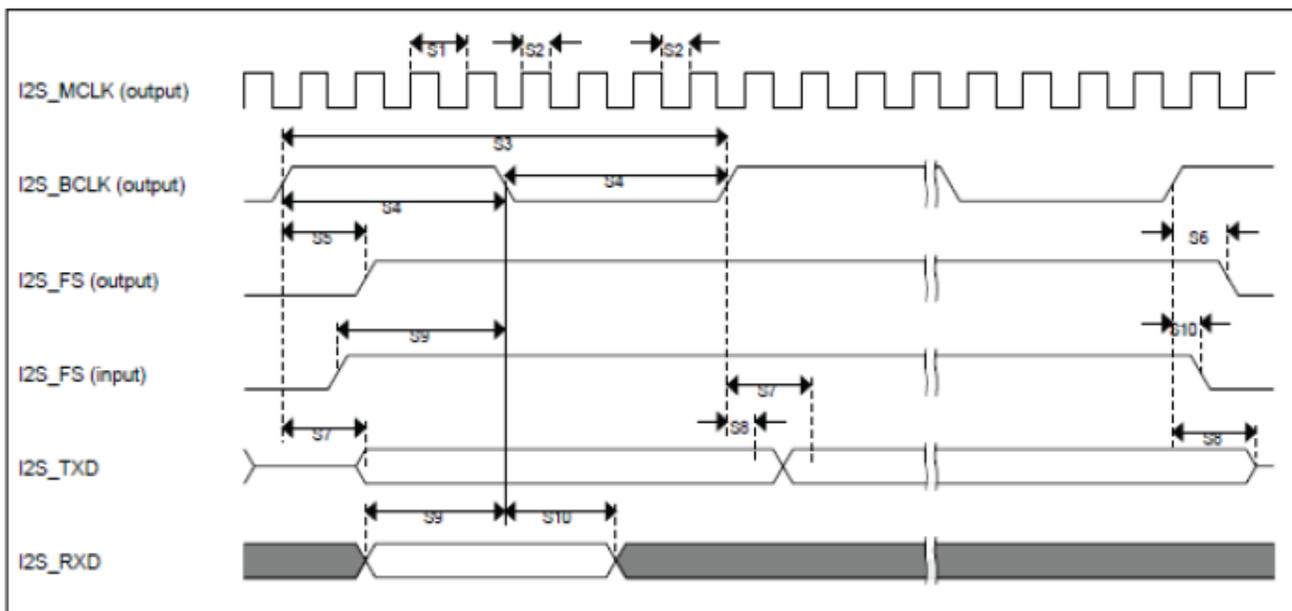
Symbol	Description	Min.	Max.	Unit
—	RXCLK frequency	—	25	MHz
MII1	RXCLK pulse width high	35%	65%	RXCLK period
MII2	RXCLK pulse width low	35%	65%	RXCLK period
MII3	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
MII4	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
—	TXCLK frequency	—	25	MHz
MII5	TXCLK pulse width high	35%	65%	TXCLK period
MII6	TXCLK pulse width low	35%	65%	TXCLK period
MII7	TXCLK to TXD[3:0], TXEN, TXER invalid	2	—	ns
MII8	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns



**Figure 21. RMII/MII transmit signal timing diagram**

**Table 43. Master mode SAI Timing (continued)**

no	Parameter	Value		Unit
		Min	Max	
S2	SAI_MCLK pulse width high/low	45%	55%	MCLK period
S3	SAI_BCLK cycle time	80	-	BCLK period
S4	SAI_BCLK pulse width high/low	45%	55%	ns
S5	SAI_BCLK to SAI_FS output valid	-	15	ns
S6	SAI_BCLK to SAI_FS output invalid	0	-	ns
S7	SAI_BCLK to SAI_TXD valid	-	15	ns
S8	SAI_BCLK to SAI_TXD invalid	0	-	ns
S9	SAI_RXD/SAI_FS input setup before SAI_BCLK	28	-	ns
S10	SAI_RXD/SAI_FS input hold after SAI_BCLK	0	-	ns



**Figure 23. Master mode SAI Timing**

**Table 44. Slave mode SAI Timing**

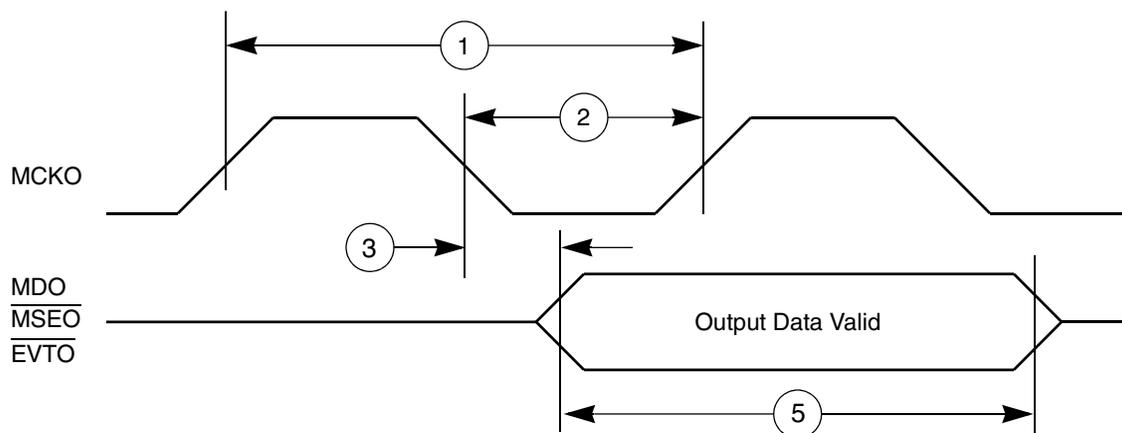
No	Parameter	Value		Unit
		Min	Max	
	Operating Voltage	2.7	3.6	V
S11	SAI_BCLK cycle time (input)	80	-	ns
S12	SAI_BCLK pulse width high/low (input)	45%	55%	BCLK period
S13	SAI_FS input setup before SAI_BCLK	10	-	ns
S14	SAI_FS input hold after SAI_BCLK	2	-	ns

Table continues on the next page...

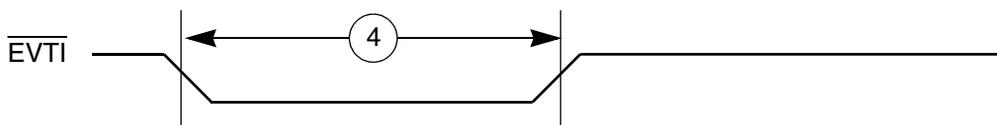
**Table 46. Nexus debug port timing <sup>1</sup> (continued)**

No.	Symbol	Parameter	Conditions	Min	Max	Unit
9	$t_{NTDIH}$ , $t_{NTMSH}$	TDI, TMS Data Hold Time	—	5	—	ns
10	$t_{JOV}$	TCK Low to TDO/RDY Data Valid	—	0	25	ns

1. JTAG specifications in this table apply when used for debug functionality. All Nexus timing relative to MCKO is measured from 50% of MCKO and 50% of the respective signal.
2. For all Nexus modes except DDR mode, MDO,  $\overline{MSEO}$ , and  $\overline{EVTO}$  data is held valid until next MCKO low cycle.
3. The system clock frequency needs to be four times faster than the TCK frequency.



**Figure 28. Nexus output timing**



**Figure 29. Nexus EVTI Input Pulse Width**

Board type	Symbol	Description	324 MAPBGA	Unit	Notes
—	$R_{\theta JB}$	Thermal resistance, junction to board	16.8	°C/W	44
—	$R_{\theta JC}$	Thermal resistance, junction to case	7.4	°C/W	55
—	$\Psi_{JT}$	Thermal characterization parameter, junction to package top natural convection	0.2	°C/W	66
—	$\Psi_{JB}$	Thermal characterization parameter, junction to package bottom natural convection	7.3	°C/W	77

- Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
- Per JEDEC JESD51-6 with the board horizontal
- Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
- Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
- Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.
- Thermal characterization parameter indicating the temperature difference between package bottom center and the junction temperature per JEDEC JESD51-12. When Greek letters are not available, the thermal characterization parameter is written as Psi-JB.

Board type	Symbol	Description	256 MAPBGA	Unit	Notes
Single-layer (1s)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	42.6	°C/W	11, 22
Four-layer (2s2p)	$R_{\theta JA}$	Thermal resistance, junction to ambient (natural convection)	26.0	°C/W	1,2,33
Single-layer (1s)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	31.0	°C/W	1,3
Four-layer (2s2p)	$R_{\theta JMA}$	Thermal resistance, junction to ambient (200 ft./min. air speed)	21.3	°C/W	1,3
—	$R_{\theta JB}$	Thermal resistance, junction to board	12.8	°C/W	44

Table continues on the next page...

Table 51. Revision History (continued)

Rev. No.	Date	Substantial Changes
Rev 2	7 August 2015	<ul style="list-style-type: none"> <li>• In features: <ul style="list-style-type: none"> <li>• Updated BAF feature with sentence, Boot Assist Flash (BAF) supports internal flash programming via a serial link (SCI)</li> <li>• Updated FlexCAN3 with FD support</li> <li>• Updated number of STMs to two.</li> </ul> </li> <li>• In Block diagram: <ul style="list-style-type: none"> <li>• Updated SRAM size from 128 KB to 256 KB.</li> </ul> </li> <li>• In Family Comparison: <ul style="list-style-type: none"> <li>• Added note: All optional features (Flash memory, RAM, Peripherals) start with lowest number or address (e.g. FlexCAN0) and end at highest available number or address (e.g. MPC574xB/D have 6 CAN, ending with FlexCAN5).</li> <li>• Revised MPC5746C Family Comparison table.</li> </ul> </li> <li>• In Ordering parts: <ul style="list-style-type: none"> <li>• Updated ordering parts diagram to include 100 MAPBGA information and optional fields.</li> </ul> </li> <li>• In table: Absolute maximum ratings <ul style="list-style-type: none"> <li>• Removed entry: 'V<sub>SS_HV</sub>'</li> <li>• Added spec for 'V<sub>DD12</sub>'</li> <li>• Updated 'Max' column for 'V<sub>INA</sub>'</li> <li>• Updated footnote for V<sub>DD_HV_ADC1_REF</sub>.</li> <li>• Added footnote to 'Conditions', All voltages are referred to V<sub>SS_HV</sub> unless otherwise specified</li> <li>• Removed footnote from 'Max', Absolute maximum voltages are currently maximum burn-in voltages. Absolute maximum specifications for device stress have not yet been determined.</li> </ul> </li> <li>• In section: Recommended operating conditions <ul style="list-style-type: none"> <li>• Added opening text: "The following table describes the operating conditions ... "</li> <li>• Added note: "V<sub>DD_HV_A</sub>, V<sub>DD_HV_B</sub> and V<sub>DD_HV_C</sub> are all ... "</li> <li>• In table: Recommended operating conditions (V<sub>DD_HV_x</sub> = 3.3 V) and (V<sub>DD_HV_x</sub> = 5 V) <ul style="list-style-type: none"> <li>• Added footnote to 'Conditions' column, (All voltages are referred to V<sub>SS_HV</sub> unless otherwise specified).</li> <li>• Updated footnote for 'Min' column to Device will be functional down (and electrical specifications as per various datasheet parameters will be guaranteed) to the point where one of the LVD/HVD resets the device. When voltage drops outside range for an LVD/HVD, device is reset.</li> <li>• Removed footnote for 'V<sub>DD_HV_A</sub>', 'V<sub>DD_HV_B</sub>', and 'V<sub>DD_HV_C</sub>' entry and updated the parameter column.</li> <li>• Removed entry : 'V<sub>SS_HV</sub>'</li> <li>• Updated 'Parameter' column for 'V<sub>DD_HV_FL_A</sub>', 'V<sub>DD_HV_ADC1_REF</sub>', 'V<sub>DD_LV</sub>'</li> <li>• Updated 'Min' column for 'V<sub>DD_HV_ADC0</sub>' 'V<sub>DD_HV_ADC1</sub>'</li> <li>• Updated 'Parameter' 'Min' 'Max' columns for 'V<sub>SS_HV_ADC0</sub>' and 'V<sub>SS_HV_ADC1</sub>'</li> <li>• Updated footnote for 'V<sub>DD_LV</sub>' to V<sub>DD_LV</sub> supply pins should never be grounded (through a small impedance). If these are not driven, they should only be left floating.</li> <li>• Removed row for symbol 'V<sub>SS_LV</sub>'</li> <li>• Removed footnote from 'Max' column of 'V<sub>DD_HV_ADC0</sub>' and 'V<sub>DD_HV_ADC1</sub>', (PA3, PA7, PA10, PA11 and PE12 ADC_1 channels are coming from V<sub>DD_HV_B</sub> domain hence V<sub>DD_HV_ADC1</sub> should be within ±100 mV of V<sub>DD_HV_B</sub> when these channels are used for ADC_1).</li> </ul> </li> </ul> </li> <li>• In table: Recommended operating conditions (V<sub>DD_HV_x</sub> = 3.3 V) <ul style="list-style-type: none"> <li>• Removed footnote from 'V<sub>IN1_CMP_REF</sub>', (Only applicable when supplying from external source).</li> </ul> </li> <li>• In table: Recommended operating conditions (V<sub>DD_HV_x</sub> = 5 V) <ul style="list-style-type: none"> <li>• Added spec for 'V<sub>IN1_CMP_REF</sub>' and corresponding footnotes.</li> </ul> </li> </ul>

*Table continues on the next page...*

Table 51. Revision History (continued)

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• In section: Voltage monitor electrical characteristics               <ul style="list-style-type: none"> <li>• Updated description for Low Voltage detector block.</li> <li>• Added note, BCP56, MCP68 and MJD31 are guaranteed ballasts.</li> </ul> </li> <li>• In table: Voltage regulator electrical specifications               <ul style="list-style-type: none"> <li>• Added footnote, Ceramic X7R or X5R type with capacitance-temperature characteristics +/-15% of -55 degC to +125degC is recommended. The tolerance +/-20% is acceptable.</li> </ul> </li> <li>• Revised table, Voltage monitor electrical characteristics</li> </ul>
		<ul style="list-style-type: none"> <li>• In section: Supply current characteristics               <ul style="list-style-type: none"> <li>• In table: Current consumption characteristics                   <ul style="list-style-type: none"> <li>• I<sub>DD_BODY_4</sub>: Updated SYS_CLK to 120 MHz.</li> <li>• I<sub>DD_BODY_4</sub>: Updated Max for T<sub>a</sub>= 105 °C and 85 °C )</li> <li>• I<sub>dd_STOP</sub>: Added condition for T<sub>a</sub>= 105 °C and removed Max value for T<sub>a</sub>= 85 °C.</li> <li>• I<sub>DD_HV_ADC_REF</sub>: Added condition for T<sub>a</sub>= 105 °C and 85 °C and removed Max value for T<sub>a</sub>= 25 °C.</li> <li>• I<sub>DD_HV_FLASH</sub>: Added condition for T<sub>a</sub>= 105 °C and 85 °C</li> </ul> </li> <li>• In table: Low Power Unit (LPU) Current consumption characteristics                   <ul style="list-style-type: none"> <li>• LPU_RUN and LPU_STOP: Added condition for T<sub>a</sub>= 105 °C and 85 °C</li> </ul> </li> <li>• In table: STANDBY Current consumption characteristics                   <ul style="list-style-type: none"> <li>• Added condition for T<sub>a</sub>= 105 °C and 85 °C for all entries.</li> </ul> </li> </ul> </li> <li>• In section: I/O parameters               <ul style="list-style-type: none"> <li>• In table: Functional Pad AC Specifications @ 3.3 V Range                   <ul style="list-style-type: none"> <li>• Updated values for 'pad_sr_hv (output)'</li> </ul> </li> <li>• In table: DC electrical specifications @ 3.3V Range                   <ul style="list-style-type: none"> <li>• Updated Min and Max values for V<sub>ih</sub> and V<sub>il</sub> respectively.</li> </ul> </li> <li>• In table: Functional Pad AC Specifications @ 5 V Range                   <ul style="list-style-type: none"> <li>• Updated values for 'pad_sr_hv (output)'</li> </ul> </li> <li>• In table DC electrical specifications @ 5 V Range                   <ul style="list-style-type: none"> <li>• Updated Min value for V<sub>hys</sub></li> </ul> </li> </ul> </li> </ul>

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Table 51. Revision History (continued)

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• In section: Reset pad electrical characteristics <ul style="list-style-type: none"> <li>• Revised table, Reset electrical characteristics</li> <li>• Deleted note, There are some specific ports that supports TTL functionality. These ports are, PB[4], PB[5], PB[6], PB[7], PB[8], PB[9], PD[0], PD[1], PD[2], PD[3], PD[4], PD[5], PD[6], PD[7], PD[8], PD[9], PD[10], and PD[11].</li> </ul> </li> <li>• In section: PORST electrical specifications <ul style="list-style-type: none"> <li>• In table: PORST electrical specifications <ul style="list-style-type: none"> <li>• Updated 'Min' value for <math>W_{NFPORST}</math></li> </ul> </li> </ul> </li> <li>• In section: Peripheral operating requirements and behaviours <ul style="list-style-type: none"> <li>• Changed section title from Input impedance and ADC accuracy to Input equivalent circuit and ADC conversion characteristics.</li> <li>• Revised table: ADC conversion characteristics (for 12-bit) and ADC conversion characteristics (for 10-bit)</li> <li>• Removed table, ADC supply configurations.</li> </ul> </li> <li>• In section: Analogue Comparator (CMP) electrical specifications <ul style="list-style-type: none"> <li>• In table: Comparator and 6-bit DAC electrical specifications <ul style="list-style-type: none"> <li>• Updated 'Max' value of <math>I_{DDL5}</math></li> <li>• Updated 'Min' and 'Max' for <math>V_{AIO}</math> and DNL</li> <li>• Updated 'Descriptor' 'Min' 'Max' od <math>V_H</math></li> <li>• Updated row for <math>t_{DHS}</math></li> <li>• Added row for <math>t_{DLS}</math></li> <li>• Removed row for <math>V_{CMPOh}</math> and <math>V_{CMPOI}</math></li> </ul> </li> </ul> </li> <li>• In section: Clocks and PLL interfaces modules <ul style="list-style-type: none"> <li>• In table: Main oscillator electrical characteristics <ul style="list-style-type: none"> <li>• <math>V_{XOSCHS}</math>: Removed values for 4 MHz.</li> <li>• <math>T_{XOSCHSSU}</math>: Updated range to 8-40 MHz.</li> </ul> </li> <li>• In table: 16 MHz RC Oscillator electrical specifications <ul style="list-style-type: none"> <li>• Updated 'Max' for <math>T_{startup}</math> and <math>T_{LTJIT}</math></li> <li>• Removed <math>F_{Untrimmed}</math> row</li> </ul> </li> <li>• In table: 128 KHz Internal RC oscillator electrical specifications <ul style="list-style-type: none"> <li>• Fosc: Removed Uncalibrated 'Condition' and updated 'Min', 'Typ', and 'Max' for Calibrated condition</li> <li>• Fosc: Updated 'Temperature dependence' and 'Supply dependence' Max values</li> </ul> </li> <li>• In table: PLL electrical specifications <ul style="list-style-type: none"> <li>• Removed entries for Input Clock Low Level, Input Clock High Level, Power consumption, Regulator Maximum Output Current, Analog Supply, Digital Supply (<math>V_{DD\_LV}</math>), Modulation Depth (Down Spread), PLL reset assertion time, and Power Consumption</li> <li>• Removed 'Typ' value for Duty Cycle at pllclkout</li> <li>• Removed 'Min' value for Lock Time in calibration mode.</li> </ul> </li> <li>• In table: Jitter calculation <ul style="list-style-type: none"> <li>• Added 1 Sigma Random Jitter and Total Period Jitter values for Long Term Jitter (Integer and Fractional Mode) rows.</li> </ul> </li> </ul> </li> </ul>
		<ul style="list-style-type: none"> <li>• In section Flash read wait state and address pipeline control settings <ul style="list-style-type: none"> <li>• In Flash Read Wait State and Address Pipeline Control: Updated APC for 40 MHz.</li> </ul> </li> <li>• Removed section: On-chip peripherals</li> </ul>

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Table 51. Revision History (continued)

Rev. No.	Date	Substantial Changes
Rev 5.1	22 May 2017	<ul style="list-style-type: none"> <li>• Removed the Introduction section from Section 4 "General".</li> <li>• In <a href="#">AC Specifications@3.3V</a> section, removed note related to Cz results and added two notes.</li> <li>• In <a href="#">AC Specifications@5V</a> section, added two notes.</li> <li>• In <a href="#">ADC Electrical Specifications</a> section, added spec value of "ADC Analog Pad" at Max leakage (standard channel)@ 105 C T<sub>A</sub> in "ADC conversion characteristics (for 10-bit)" table.</li> <li>• In <a href="#">PLL Electrical Specifications</a> section, updated the first footnote of "Jitter calculation" table.</li> <li>• In <a href="#">Analog Comparator Electrical Specifications</a> section, updated the TDLS (propagation delay, low power mode) max value in "Comparator and 6-bit DAC electrical specifications" table to 21 us.</li> <li>• In <a href="#">Recommended Operating Conditions</a> section, updated the footnote link to T<sub>A</sub> in "Recommended operating conditions (V DD_HV_x = 5V)" table.</li> </ul>

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